SILICON POWER TRANSISTOR 2SC4551

NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC4551 is a power transistor developed for high-speed switching and features low VCE(sat) and high hFE. This transistor is ideal for use in drivers such as DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

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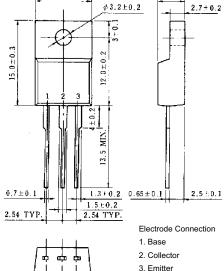
- High hFE and low VCE(sat): $h_{FE} \ge 100 (V_{CE} = 2 V, I_{C} = 2 A)$ $V_{CE(sat)} \le 0.3 \text{ V} (I_{C} = 6 \text{ A}, I_{B} = 0.3 \text{ A})$
- · Mold package that does not require an insulating board or insulation bushing

Symbol	Ratings	Unit
Vсво	100	V
VCEO	60	V
VEBO	7.0	V
IC(DC)	10	А
IC(pulse)*	20	А
IB(DC)	5.0	А
P⊤ (Tc = 25°C)	30	W
P⊤ (Ta = 25°C)	2.0	W
Tj	150	°C
Tstg	–55 to +150	°C
	VCBO VCEO VEBO IC(DC) IC(pulse)* IB(DC) PT (Tc = 25°C) PT (Ta = 25°C) Tj	VCBO 100 VCEO 60 VEBO 7.0 Ic(DC) 10 Ic(pulse)* 20 IB(DC) 5.0 PT (Tc = 25°C) 30 PT (Ta = 25°C) 2.0 T _j 150

ABSOLUTE MAXIMUM RATINGS (Ta = 25° C)

* PW \leq 300 μ s, duty cycle \leq 10%

10.0±0.3 φ3.2±0,2



PACKAGE DRAWING (UNIT: mm)

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

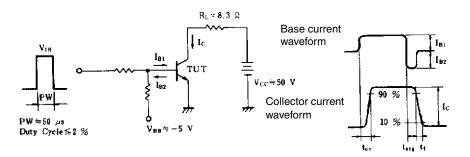
Parameter	Symbol	Conditions MIN.		TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = 6.0 A, I _B = 0.6 A, L = 1 mH				V
Collector to emitter voltage	VCEX(SUS)	Ic = 6.0 A, I _{B1} = $-I_{B2}$ = 0.6 A, V _{BE(OFF)} = -1.5 V, L = 180 μ H, clamped	60			V
Collector cutoff current	Ісво	$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$			10	μA
Collector cutoff current	ICER	$V_{CE} = 60 \text{ V}, \text{ R}_{BE} = 50 \Omega, \text{ Ta} = 125^{\circ}\text{C}$			1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = 60 \text{ V}, \text{ V}_{BE(OFF)} = -1.5 \text{ V}$			10	μA
Collector cutoff current	ICEX2	$V_{CE} = 60 \text{ V}, V_{BE(OFF)} = -1.5 \text{ V},$ Ta = 125°C			1.0	mA
Emitter cutoff current	Іево	V _{EB} = 5.0 V, Ic = 0			10	μA
DC current gain	hfe1*	Vce = 2.0 V, Ic = 1.0 A	100			
DC current gain	hfe2*	Vce = 2.0 V, Ic = 2.0 A	100	200	400	
DC current gain	hfe3*	Vce = 2.0 V, Ic = 6.0 A	60			
Collector saturation voltage	V _{CE(sat)1} *	Ic = 6.0 A, I _B = 0.3 A			0.3	V
Collector saturation voltage	VCE(sat)2*	Ic = 8.0 A, I _B = 0.4 A			0.5	V
Base saturation voltage	V _{BE(sat)1} *	Ic = 6.0 A, IB = 0.3 A			1.2	V
Base saturation voltage	VBE(sat)2*	Ic = 8.0 A, IB = 0.4 A			1.5	V
Collector capacitance	Cob	Vсв = 10 V, IE = 0, f = 1.0 MHz		150		pF
Gain bandwidth product	f⊤	Vce = 10 V, Ic = 1.0 A		140		MHz
Turn-on time	ton	$I_{C} = 6.0 \text{ A}, \text{ R}_{L} = 8.3 \Omega,$			0.3	μs
Storage time	tstg	I _{B1} = −I _{B2} = 0.3 A, Vcc ≅ 50 V Refer to the test circuit.			1.5	μs
Fall time	tr				0.3	μs

* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

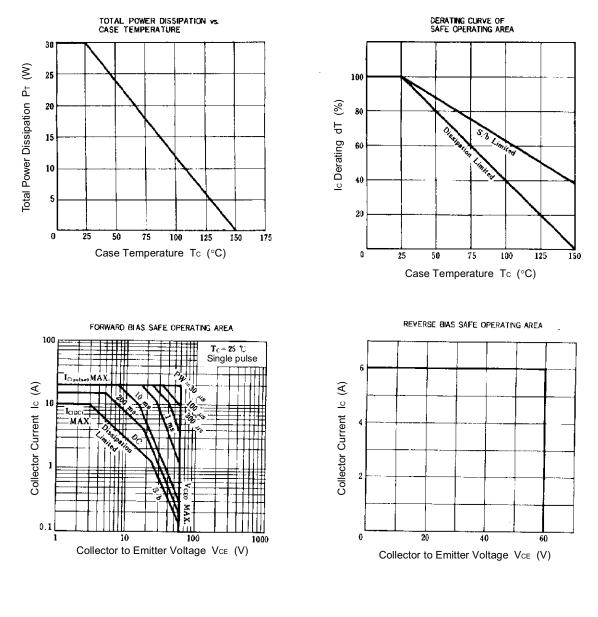
hfe CLASSIFICATION

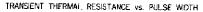
Marking	М	L	к
hFE2	100 to 200	150 to 300	200 to 400

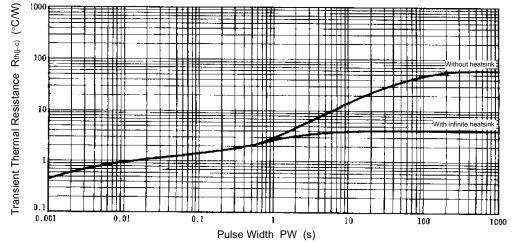
SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

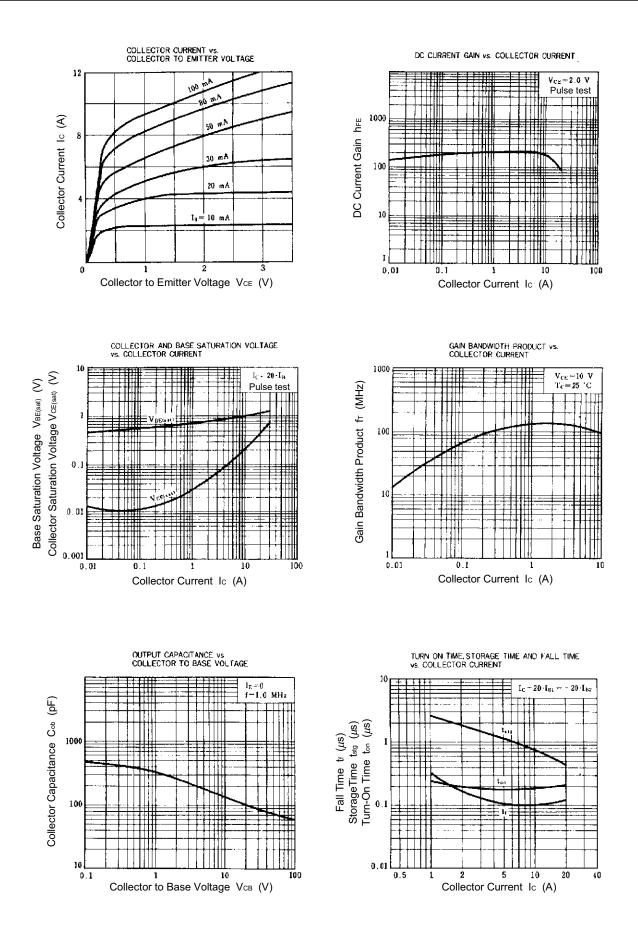


TYPICAL CHARACTERISTICS (Ta = 25°C)









[MEMO]

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